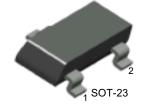


### BC846/847/848/849/850

# Switching and Amplifier Applications Suitable for automatic insertion in thick and thin-film circuits

- Low Noise: BC849, BC850
- Complement to BC856 ... BC860



### **NPN Epitaxial Silicon Transistor**

1. Base 2. Emitter 3. Collector

### **Absolute Maximum Ratings** T<sub>a</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CBO</sub>	Collector-Base Voltage		
020	: BC846	80	V
	: BC847/850	50	V
	: BC848/849	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage		
020	: BC846	65	V
	: BC847/850	45	V
	: BC848/849	30	V
V <sub>EBO</sub>	Emitter-Base Voltage		
250	: BC846/847	6	V
	: BC848/849/850	5	V
I <sub>C</sub>	Collector Current (DC)	100	mA
P <sub>C</sub>	Collector Dissipation	310	mW
TJ	Junction Temperature	150	°C
T <sub>STG</sub>	Storage Temperature	-65 ~ 150	°C

### **Electrical Characteristics** $T_a$ =25°C unless otherwise noted

	u					
Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
I <sub>CBO</sub>	Collector Cut-off Current	V <sub>CB</sub> =30V, I <sub>E</sub> =0			15	nA
h <sub>FE</sub>	DC Current Gain	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA	110		800	
V <sub>CE</sub> (sat)	Collector-Emitter Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA I <sub>C</sub> =100mA, I <sub>B</sub> =5mA		90 200	250 600	mV mV
V <sub>BE</sub> (sat)	Collector-Base Saturation Voltage	I <sub>C</sub> =10mA, I <sub>B</sub> =0.5mA I <sub>C</sub> =100mA, I <sub>B</sub> =5mA		700 900		mV mV
V <sub>BE</sub> (on)	Base-Emitter On Voltage	V <sub>CE</sub> =5V, I <sub>C</sub> =2mA V <sub>CE</sub> =5V, I <sub>C</sub> =10mA	580	660	700 720	mV mV
f <sub>T</sub>	Current Gain Bandwidth Product	V <sub>CE</sub> =5V, I <sub>C</sub> =10mA, f=100MHz		300		MHz
C <sub>ob</sub>	Output Capacitance	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		3.5	6	pF
C <sub>ib</sub>	Input Capacitance	V <sub>EB</sub> =0.5V, I <sub>C</sub> =0, f=1MHz		9		pF
NF	Noise Figure : BC846/847/848 : BC849/850 : BC849 : BC850	$V_{CE}$ =5V, $I_{C}$ =200 $\mu$ A f=1KHz, $R_{G}$ =2K $\Omega$ $V_{CE}$ =5V, $I_{C}$ =200 $\mu$ A $R_{G}$ =2K $\Omega$ , f=30~15000Hz		2 1.2 1.4 1.4	10 4 4 3	dB dB dB dB

	$\sim$		4.
h		assific	ation
	•	4001110	auon

Classification	А	В	С		
h <sub>FE</sub>	110 ~ 220	200 ~ 450	420 ~ 800		

## Marking Code

Typo	846		847		848		849		850						
Type	Α	В	С	Α	В	С	Α	В	С	Α	В	С	Α	В	С
Mark	8AA	8AB	8AC	8BA	8BB	8BC	8CA	8CB	8CC	8DA	8DB	8DC	8EA	8EB	8EC

## **Typical Characteristics**

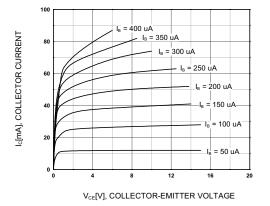


Figure 1. Static Characteristic

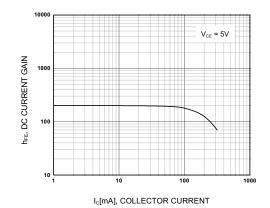


Figure 2. DC current Gain

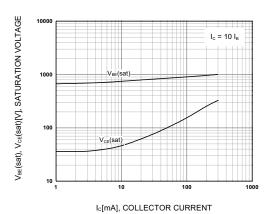


Figure 3. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

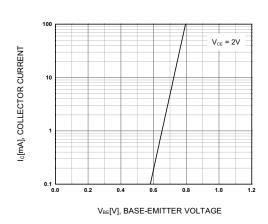


Figure 4. Base-Emitter On Voltage

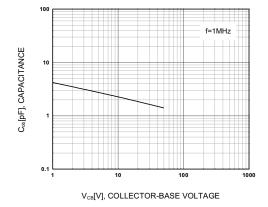


Figure 5. Collector Output Capacitance

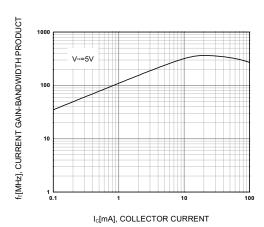
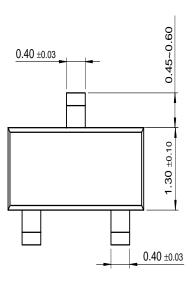


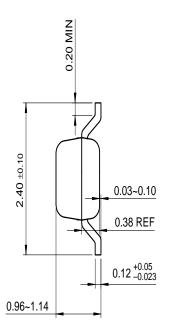
Figure 6. Current Gain Bandwidth Product

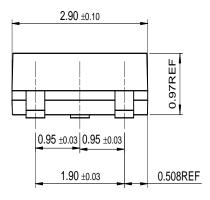
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## **Package Demensions**

## **SOT-23**







**Dimensions in Millimeters** 

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.		
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.		

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